MSA-0770
Cascadable Silicon Bipolar MMIC Amplifier

Data Sheet

Description

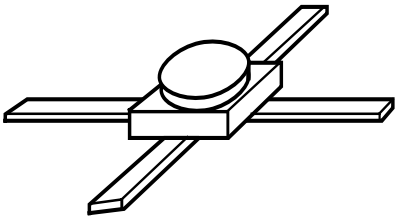
The MSA-0770 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, high reliability package. This MMIC is designed for use as a general purpose 50Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Avago's 10 GHz f_T, 25 GHz f_{MAX}, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

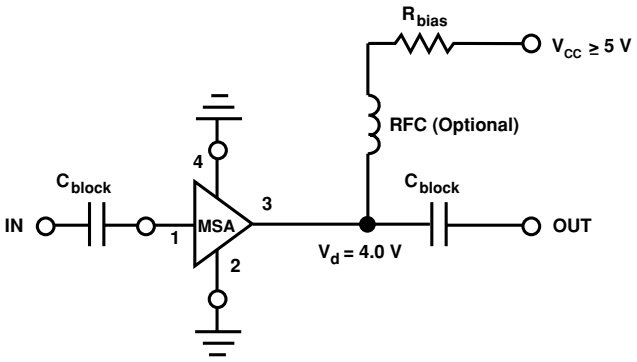
Features

- Cascadable 50Ω Gain Block
- Low Operating Voltage: 4.0 V Typical V_d
- 3 dB Bandwidth: DC to 2.5 GHz
- 13.0 dB Typical Gain at 1.0 GHz
- Unconditionally Stable (k>1)
- Hermetic, Gold-ceramic Microstrip Package

70 mil Package



Typical Biasing Configuration



MSA-0770 Absolute Maximum Ratings

Parameter	Absolute Maximum[1]
Device Current	60 mA
Power Dissipation[2,3]	275 mW
RF Input Power	+13 dBm
Junction Temperature	200°C
Storage Temperature	–65 to 200°C

Thermal Resistance[2,4]:

$\theta_{jc} = 130°C/W$

Notes:
1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{CASE} = 25°C$.
3. Derate at 7.7 mW/°C for $T_C > 164°C$.
4. Ths small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods.

Electrical Specifications[1], $T_A = 25°C$

Symbol	Parameters and Test Conditions: $I_d = 22$ mA, $Z_O = 50\ \Omega$		Units	Min.	Typ.	Max.
G_P	Power Gain ($\|S_{21}\|^2$)	f = 0.1 GHz	dB	12.5	13.5	14.5
ΔG_P	Gain Flatness	f = 0.1 to 1.5 GHz	dB		±0.6	±1.0
$f_{3\ dB}$	3 dB Bandwidth		GHz		2.5	
VSWR	Input VSWR	f = 0.1 to 2.5 GHz			2.0:1	
	Output VSWR	f = 0.1 to 2.5 GHz			1.6:1	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		4.5	
$P_{1\ dB}$	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		5.5	
IP_3	Third Order Intercept Point	f = 1.0 GHz	dBm		19.0	
t_D	Group Delay	f = 1.0 GHz	psec		130	
V_d	Device Voltage		V	3.6	4.0	4.4
dV/dT	Device Voltage Temperature Coefficient		mV/°C		–7.0	

Note:
1. The recommended operating current range for this device is 15 to 40 mA. Typical performance as a function of current is on the following page.

MSA-0770 Typical Scattering Parameters ($Z_0 = 50\ \Omega$, $T_A = 25°C$, $I_d = 22$ mA)

Freq.	S_{11}			S_{21}			S_{12}		S_{22}	
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.04	–7	13.5	4.74	175	–18.6	.118	2	.20	–10
0.2	.05	–11	13.5	4.72	170	–18.4	.120	2	.19	–18
0.4	.06	–24	13.4	4.70	160	–18.4	.121	6	.20	–34
0.6	.08	–38	13.4	4.65	151	–18.1	.124	7	.21	–50
0.8	.10	–48	13.2	4.58	141	–17.8	.133	9	.23	–76
1.0	.12	–58	13.0	4.47	131	–17.5	.133	9	.23	–76
1.5	.20	–82	12.3	4.12	107	–16.6	.148	10	.23	–101
2.0	.30	–107	11.6	3.82	85	–15.7	.163	8	.22	–116
2.5	.37	–123	10.4	3.33	70	–15.3	.171	7	.19	–116
3.0	.42	–140	9.0	2.83	52	–15.4	.170	3	.20	–111
3.5	.46	–154	7.7	2.42	37	–15.4	.170	1	.23	–107
4.0	.47	–167	6.4	2.08	23	–15.5	.169	–4	.29	–107
5.0	.47	163	4.2	1.63	–1	–15.5	.167	–9	.35	–116
6.0	.51	131	2.3	1.30	–23	–15.9	.160	–11	.38	–133

Typical Performance, $T_A = 25°C$

(unless otherwise noted)

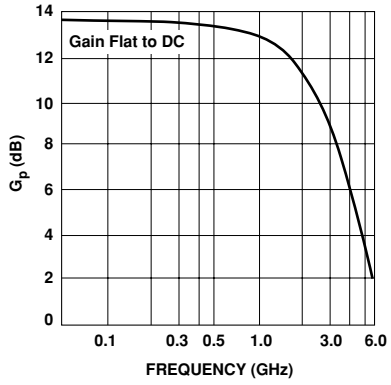


Figure 1. Typical Power Gain vs. Frequency, $I_d = 22$ mA.

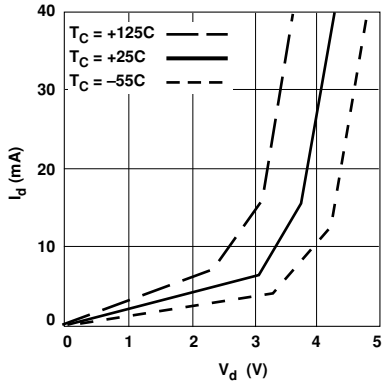


Figure 2. Device Current vs. Voltage.

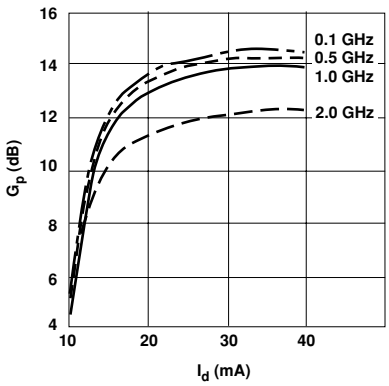


Figure 3. Power Gain vs. Current.

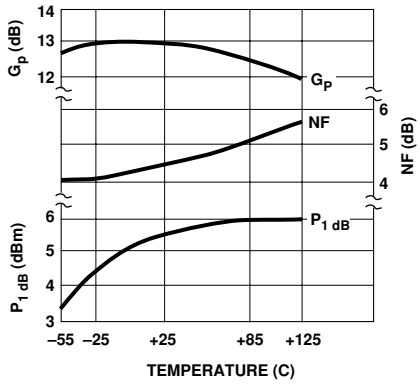


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 1.0 GHz, $I_d = 22$ mA.

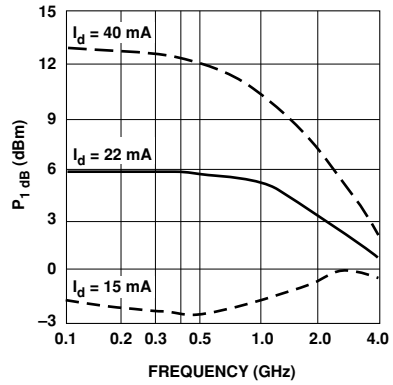


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

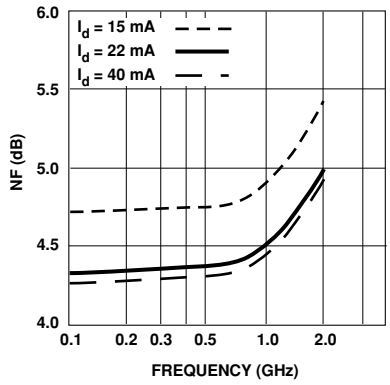
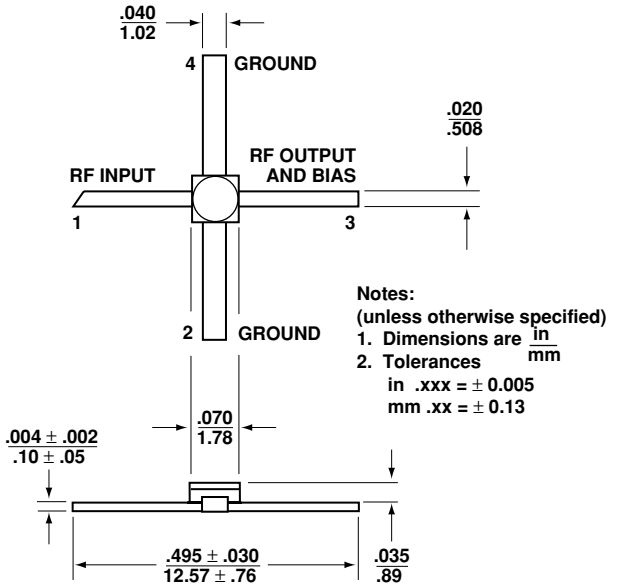


Figure 6. Noise Figure vs. Frequency.

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0770	100	Bulk

70 mil Package Dimensions



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